Chroma signal frequency converter BA7049S/BA7049FS

The BA7049S and BA7049FS convert NTSC, PAL-M and PAL-N chroma signal subcarrier frequencies to the PAL format 4.433619MHz to allow PAL format processing circuits to handle record and playback signals for these other formats. These ICs facilitate the development of multi-format VCRs.

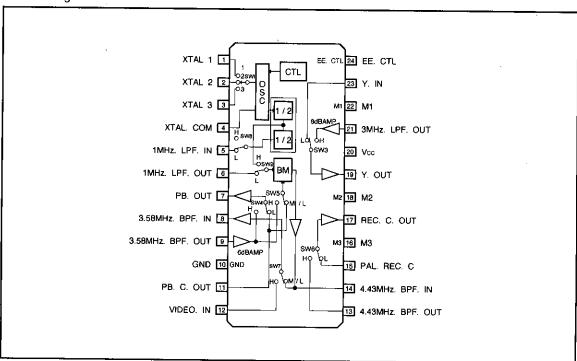
Applications

Multi-format VHS VCRs.

Features

- Converts record and playback signals to standard format.
- 2)Compatible with up to three other formats in addition to PAL.
- 3)Y and chroma system filter switches are all built-in. Few external components required.

Block diagram



NTSC/PAL format converters

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Applied voltage	VCC Max.	8.0	٧
Power dissipation	Pd	800 *	mW
Operating temperature	Topr	-25~70	Ĉ
Storage temperature	Tstg	−55 ~125	°C

^{*} Reduced by 8.0mW for each increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Operating supply voltage	Vcc	4.5	5.0	5.5	٧

●Electrical characteristics (Unless otherwise specified: Ta=25°C and Vcc=5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	C	conditions
Circuit current	lee	20.5	31.0	41.5	mA		
0dB amplifier voltage gain	G₀	-0.5	0.0	+0.5	dB	f=1MHz	Vin=0.5V _{PP}
0dB amplifier frequency characteristic	fo	-2.0	+0.0	+1.0	dΒ	f=5MHz / 1MHz	Vin≔0.5V _{PP}
6dB amplifier voltage gain	Gé	+5.5	+6.0	+6.5	dB	f=1MHz	Vin=0.25V _{PP}
6dB amplifier frequency characteristic	f ₆	-2.0	+0.0	+1.0	dB	f=5MHz / 1MHz	Vin=0.25V _{PP}
Interchannel crosstalk	Ст	_	-45	-40	dB	f=4.43MHz	Vin=0.5V _{PP}
Frequency divider output level	Voe .	0.50	0.85	1.30	VPP	When 3.4MHz/3.58	BMHz X'tal is oscillating
BM output level	Vов	125	185	245	mV _{PP}	f=3.58MHz	Vin=0.3V _{PP}
BM carrier leak	CLe	_	-40	-30	dB	f=3.58MHz	Vin=0.3V _{PP}
Switch voltage 1	V _{TH1}	1.00	2.00	3.00	٧	M1, M2, M3	
Switch voltage 2	V _{TH2}	3.50	3.90	4.35	٧	EE. CTL	

●Guaranteed design items (Unless otherwise specified: Ta=25°C and Vcc=5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit		Conditions
0dB amplifier voltage gain	G₀	-1.0	0.0	+0.5	dB	f=4MHz	Vin≕0.5V _{PP}

O Not designed for radiation resistance.

●Logic truth table

M1	M2	SW1	
L	٦	_	
н	L	1	
L	н	2	
н ,	н	3	

M1	M2	SW3, 4, 6
Ł	L	L
Н	L	Н
L	н	н
н	Н	Н

M1	M2	SW8
L	L	Н
н	L	L
L	Н	Ļ
Н	н	L

мз	SW2
L	L
Н	Н

EE. CTL	SW5, 7
н	н
	M/L

●Input / output circuits

Din No	C. makia m	Pin v	oltage	Input/output	Equivalent circuit
Pin No.	Function	DC	AC	resistance	Equivalent circuit
1	XTAL 1	2.0V	1.0VPP	150 Ω	CTL — 100 100 1
2	XTAL 2	2.0V	1.0Vpp	150 Ω	CTL — 100 2

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components	
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Pin No.	Function	Pin vo		Input/output	Equivalent circuit
FIIT NO.	Tunction	DC	AC	resistance	
3	XTAL 3	2.0V	1.0Vpp	150 Ω	CTL — 100 100 4 A
4	XTAL. COM	2.0V	1.7Vpp	5kΩ	\$10k \$10k
5	LPF. IN (1MHz)	4.0V	850mVpp	130 Ω	100 5 mA
6	LPF, OUT (1MH)	2.0V	500mVpp	20kΩ	120 ≠ 100 μ A 6
7	PB. OUT	2.0V	300mVpp	130 Ω	2V 7 7

Pin No.	Function	Pin voltage		Input/output	
· III NO.	- unction	DC	AC	resistance	Equivalent circuit
8	BPF. IN (3.58MHz)	2.3V	1.0Vpp	150 Ω	2V 3.2k 100 B
9	BPF. OUT (3.58MHz)	2.0V	150mV _{PP}	20kΩ	20k 100 B 100 µ A
10	GND	ov	_	-	10
11	PB. C. OUT	2.0V	300mVpp	20κΩ	20k SW4 SW5
12	VIDEO. IN	2.0V	300mVpp	20kΩ	20k 100 μA

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Pin No	Function	Pin voltage		Input/output	Equivalent circuit
Pin No.		DC	AC	resistance	Equivalent Gilcuit
13	BPF. OUT (4.43MHz)	2.0V	150mVpp	20kΩ	72V ₹100 ↓ ⊗ 100 μ A
14	BPF. IN (4.43MHz)	2.2V	1.0Vpp	130 Ω	2.25V 2.8k 100 14
15	PAL. REC. C	2.0V	150mVpp	20kΩ	20k
16	мз	60mV	_	50kΩ	16 \$26k \$30k
17	REC. C. OUT	2.0V	150mVpp	130 Ω	2V 2k 100 17

Pin No.	Function	Pin voltage		Input/output	Equivalent circuit
		DC	AC	resistance	
18	M2	60mV	_	50kΩ	18 50k 30k
19	Y. OUT	2.0V	400mVpp	130 Ω	2V 2k 100 19
20	vec	5.0V	_	_	20
21	LPF. OUT (3MHz)	2.0V	200mV _{PP}	20kΩ	20k 100 μ A 21
22	M1	60mV	_	50kΩ	22 50k 30k

Pin No.	Function	Pin voltage		Input/output	<u> </u>
		DÇ	AC	resistance	Equivalent circuit
23	Y. IN	2.0V	400mVpp	20kΩ	20k 100 ↓8 100 μ A
24	EE. CTL	0.5V	_	2MΩ or more	24 13k \$10k \$10k \$20k \$22.5k \$20k \$22.5k \$40k

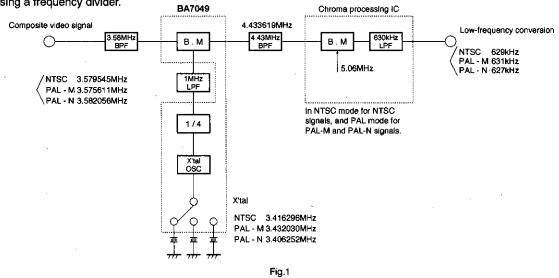
Circuit operation

Recording

A balance modulator is used to convert the subcarrier frequency of the input chroma signal to PAL-format subcarrier frequency.

The local oscillator used for frequency conversion uses a x'tal to generate a frequency of four times the required frequency. This frequency is divided-by-four internally using a frequency divider.

Signals converted to the PAL-format subcarrier frequency by this IC are input to a chroma processing IC equipped with a PAL filter. By operating the circuit in NTSC mode for NTSC signals and in PAL mode for PAL-M and PAL-N signals, a low-frequency output signal in the converted format is obtained.



Circuit operation

Playback

During playback, an NTSC or PAL signal with a subcarrier frequency of 4.433619MHz is output. Using the opposite procedure to that of recording, these signals are con verted to NTSC, PAL-M, or PAL-N subcarrier-frequency signals.

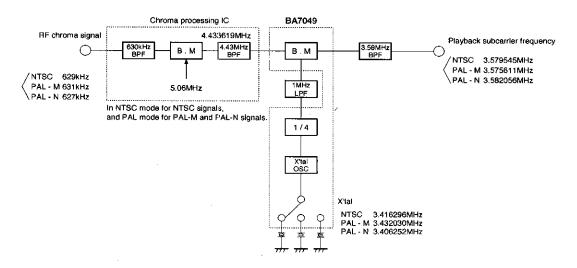


Fig.2

Application example

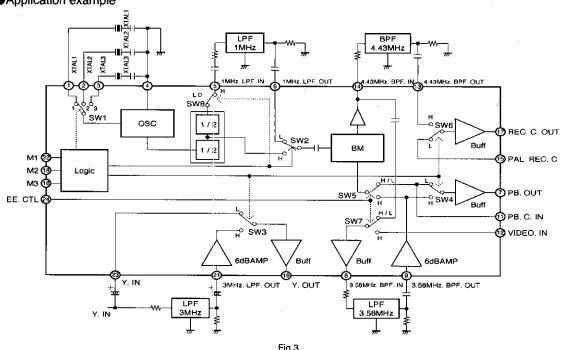


Fig.3

NTSC/PAL format converters

VCR components

Operation notes

External components for the x'tal oscillator

The external circuit for the oscillator is shown below. The capacitor values are for reference only. Determine suitable values for the capacitors after consulting with the crystal manufacturer.

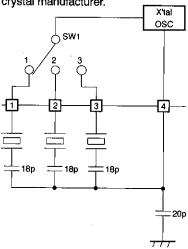
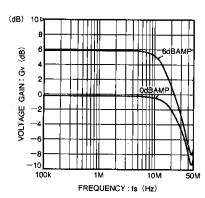
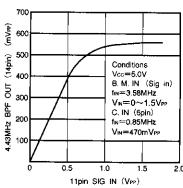


Fig. 4

●Electrical characteristic curves (Ta=25°C)





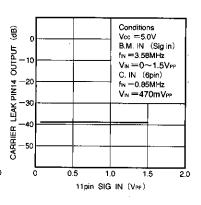


Fig. 5 SW frequency characteristics

Fig. 6 B.M.D. range characteristics

Fig. 7 B.M. carrier leak characteristics

6dB AMP 9pin in → 7pin out 21pin in → 19pin out OdB AMP 11pin in → 7pin out 12pin in → 8pin out 13pin in → 17pin out 15pin in → 17pin out 23pin in → 19pin out

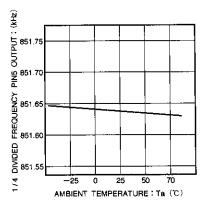


Fig. 8 1/4 frequency divider frequency vs. ambient temperature characteristics.

●External dimensions (Units: mm)

